# High Power Laser Diode B-mount



# Part Number: B-103

High Power B-mount Multi-Mode Fabry-Perot CW Wavelength at 1310nm Lensed Options Available

## Features

- High Output Power
- High Dynamic Range
- High Efficiency
- Standard B-mount
- Cost Effective

# Application

Professional Medical





SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary, we will further optimize the design of our InP & GaSb laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements.



## Specification

B-103



Optical	Symbol	Тур.	Units
Center Wavelength	λ <sub>c</sub>	1310	nm (±20)
Output Power (CW)*	Pout	5.7	watts (±10%)
Emitter Width	W	95	μm
Spectral Width FWHM	Δλ	15	nm
Slope Efficiency	η	0.4	W/A
Fast Axis Div.	Θ⊥	28	deg FWHM
Slow Axis Div.	Θ <sub>II</sub>	9	deg FWHM
Electrical	Symbol		Units
Power Conversion Eff.	η	23	%
Threshold Current	Ітн	0.5	А
			<i>,</i> ,
Operating Current	l <sub>op</sub>	14	A
Operating Current Operating Voltage	l <sub>op</sub> V <sub>op</sub>		
		14	A
Operating Voltage	V <sub>op</sub>	14 1.8	A V

\*Specified values are rated at a constant heat sink temperature of 20°C. \*\*High temperature operation will reduce performance and MTTF. Unless otherwise indicated all values are nominal.

#### \*Available Lenses

Suffix	Description
-108	Lens Matched f=171µm, 5mm Lg
-118	Lens Collimated <10mrad f=274µm, 5mm Lg
-134	Lens Matched f=274µm, 5mm Lg
-141	Lens, FAC, f=590µm, 5mm Lg, Collimated 5mrad

# **High Power Laser Diode B-mount**

### SemiNex Laser Diodes B-103

#### Graphs & Data

8 LIV Plot

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Typical B-mount L-I-V Characteristics

3.5

3.0

2.5

/oltage 2.0

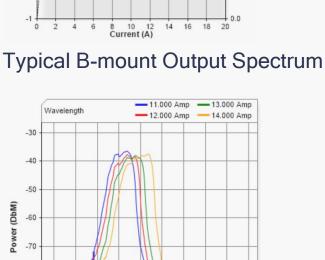
Optical Power (W) - Voltage (V)

#### **Optical Power (W)** 1.5 3 2 1.0 1 0.5 0 + 0.0 20 14 16 6 8 10 12 Current (A) 18

#### Power (DbM) -60 -70 -80 -90 -100 1,280 1,290 1,300 1,310 1,320 1,330 1,340 1,350 1,360 1,370 Wavelength (nm)



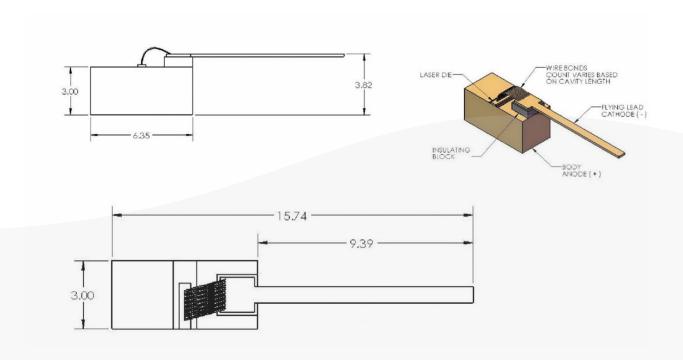








### Mechanical Drawing



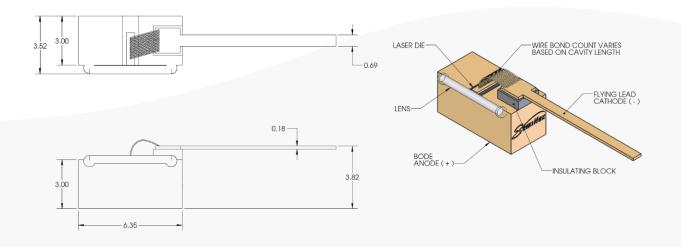
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# High Power Laser Diode B-mount



Mechanical Drawing B-103-108 B-103-118 B-103-134 B-103-141



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